















**ESD** 

TVS

MOS

LDO

Diode

Sensor

DC-DC

# **Product Specification**

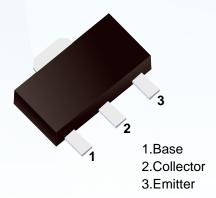
Domestic Part Number	B772
Overseas Part Number	B772
▶ Equivalent Part Number	B772





#### PNP Transistors

- Features
- PNP transistor High current output up to 3A
- Low Saturation Voltage
- Complement to 2SD882



■ Simplified outline(SOT-89)

#### ■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	Vсво	-40	V
Collector to Emitter Voltage	VCEO	-30	V
Emitter to Base Voltage	VEBO	-6	V
Collector Current to Continuous	Ic	-3	А
Collector Dissipation	Pc	0.5	W
Junction Temperature	TJ	150	$^{\circ}\!\mathbb{C}$
Storage Temperature	Tstg	-55 to 150	$^{\circ}\mathbb{C}$

#### ■ Electrical Characteristics Ta = 25°C

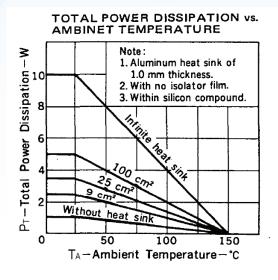
Parameter	Symbol	Test Conditions		Тур	Max	Unit
Collector-base breakdown voltage	Vсво	Ic=-100uA ,IE=0	-40			V
Collector-emitter breakdown voltage	VCEO	Ic= -10 mA , Iв=0	-30			V
Emitter-base breakdown voltage	VEBO	IE= -100 uA ,Ic=0	-6			V
Collector cut-off current	Ісво	Vcb=-40 V , IE=0			-1	μΑ
Emitter cut-off current	ІЕВО	VEB=-6V , IC=0			-1	μΑ
DC current gain	hFE	Vce= -2V, Ic= -1A	60		400	
	IIFE	Vc=-2V, Ic= -100mA	32			
Collector-emitter saturation voltage	VCE(sat)	Ic=-2A, IB=- 0.2A			-0.5	V
Base-emitter saturation voltage	VBE(sat)	Ic=-2A, I <sub>B</sub> = -0.2A			-1.5	V
Transition frequency	f <sub>T</sub>	Vc=-5 V, Ic=-0.1mA,f = 10MHz	50			MHz

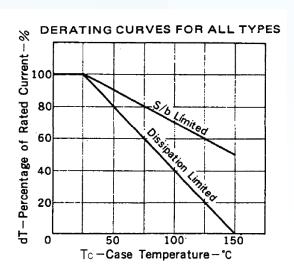
#### ■ Classification of hfe(1)

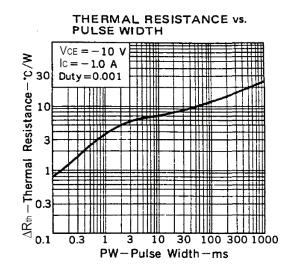
Type	2SB772-R	2SB772-Q	2SB772-P	2SB772-E
Range	60-120	100-200	160-320	200-400

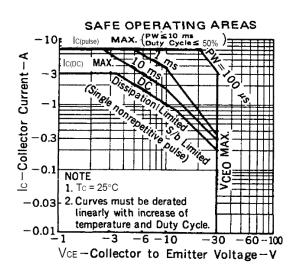


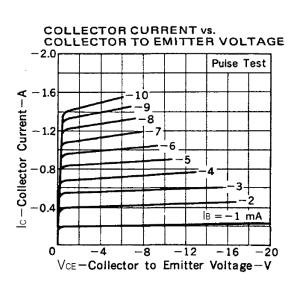
#### ■ Typical Characteristics

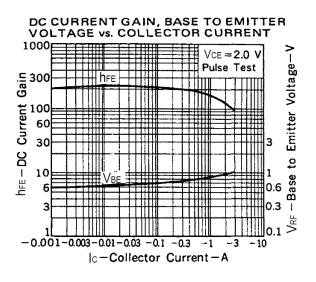




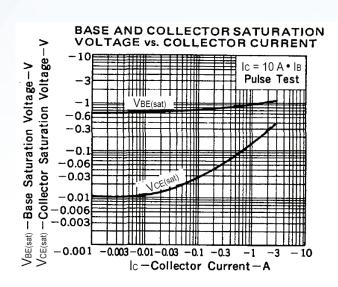


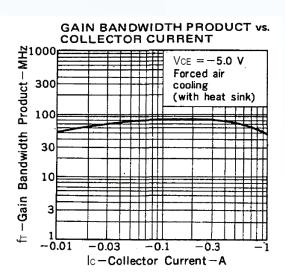




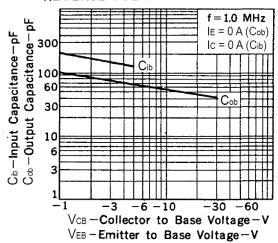






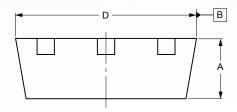


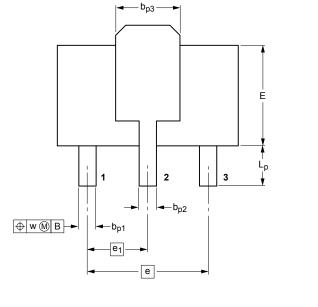
### INPUT AND OUTPUT CAPACITANCE vs. REVERSE VOLTAGE

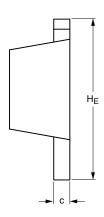




#### **■** SOT-89









#### **DIMENSIONS** (mm are the original dimensions)

UNIT	Α	b <sub>p1</sub>	b <sub>p2</sub>	b <sub>p3</sub>	С	D	E	e	e <sub>1</sub>	HE	Lp	w
mm	1.6 1.4	0.48 0.35	0.53 0.40	1.8 1.4	0.44 0.23	4.6 4.4	2.6 2.4	3.0	1.5	4.25 3.75	1.2 0.8	0.13



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